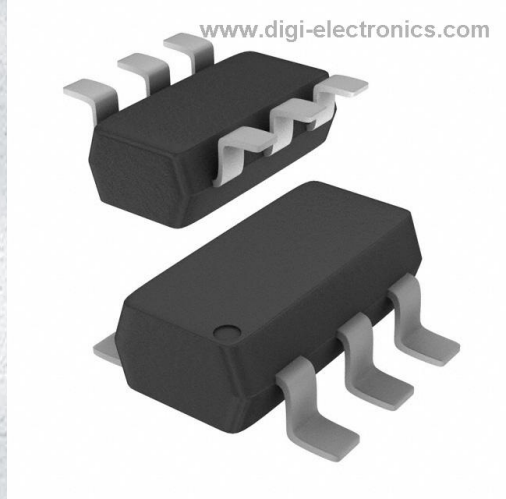
IMH20TR1G Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	IMH20TR1G-DG
Manufacturer	onsemi
Manufacturer Product Number	IMH20TR1G
Description	TRANS PREBIAS 2NPN 15V SC74R
Detailed Description	Pre-Biased Bipolar Transistor (BJT) 2 NPN - Pre-Biased (Dual) 15V 600mA 300mW Surface Mount SC-74R

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IMH20TR1G	onsemi
Series:	Product Status:
-	Active
Transistor Type:	Current - Collector (Ic) (Max):
2 NPN - Pre-Biased (Dual)	600mA
Voltage - Collector Emitter Breakdown (Max):	Resistor - Base (R1):
15V	2.2kOhms
Resistor - Emitter Base (R2):	DC Current Gain (hFE) (Min) @ Ic, Vce:
-	100 @ 50mA, 5V
Vce Saturation (Max) @ Ib, Ic:	Current - Collector Cutoff (Max):
80mV @ 2.5mA, 50mA	-
Frequency - Transition:	Power - Max:
-	300mW
Mounting Type:	Package / Case:
Surface Mount	SC-74, SOT-457
Supplier Device Package:	Base Product Number:
SC-74R	IMH20

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	

onsemi

DATA SHEET
www.onsemi.com

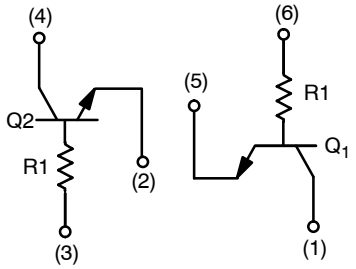
Dual Bias Resistor Transistor

NPN Surface Mount

IMH20TR1G

- Low V_{CC} (sat) 80 mV max at IC/IB = 50 mA/2.5 mA
- High Current: I_C = 600 mA max
- This is a Pb−Free Device

SC−74R
318AA
Style 21



SC−74

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Value	Unit
Collector−Base Voltage	$V_{(BR)CBO}$	30	Vdc
Collector−Emitter Voltage	$V_{(BR)CEO}$	15	Vdc
Emitter−Base Voltage	$V_{(BR)EBO}$	5.0	Vdc
Collector Current − Continuous	I_C	600	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation*	P_D	300	mW
Junction Temperature	T_J	150	°C
Storage Temperature	T_{stg}	−55 to +150	°C

*Total for both Transistors.

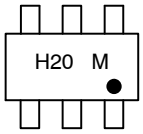
Q1 + Q2: NPN

ELECTRICAL CHARACTERISTICS
(T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Collector−Emitter Breakdown Voltage (I_C = 1.0 mAdc, I_B = 0)	$V_{(BR)CEO}$	15	−	Vdc
Collector−Base Breakdown Voltage (I_C = 50 μAdc, I_E = 0)	$V_{(BR)CBO}$	30	−	Vdc
Emitter−Base Breakdown Voltage (I_E = 50 μAdc, I_C = 0)	$V_{(BR)EBO}$	5.0	−	Vdc
Collector−Base Cutoff Current (V_{CB} = 20 Vdc, I_E = 0)	I_{CBO}	−	0.5	μAdc
Emitter−Base Cutoff Current (V_{EB} = 4.0 V, I_C = 0)	I_{EBO}	−	0.5	μAdc
DC Current Gain (Note 1) (V_{CE} = 5.0 Vdc, I_C = 50 mAdc)	h_{FE}	100	600	−
Collector−Emitter Saturation Voltage (I_C = 50 mAdc, I_B = 2.5 mAdc)	$V_{CE(sat)}$	−	80	mV
Input Resistance	R_1	1.54	2.86	kΩ

1. Pulse Test: Pulse Width ≤ 300 μs, D.C. ≤ 2%.

MARKING DIAGRAM



H20 = Specific Device Code
M = Date Code

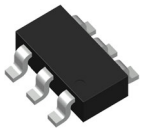
ORDERING INFORMATION

Device	Package	Shipping†
IMH20TR1G	SC−74R	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

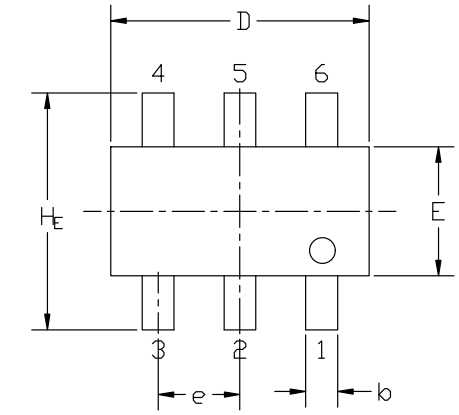
Publication Order Number:
IMH20TR1G/D

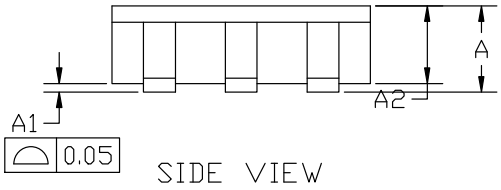
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

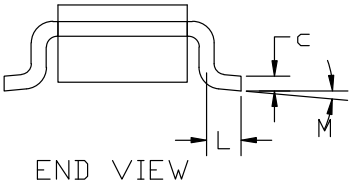


SC74−6 3.00x1.50x0.90, 0.95P
CASE 318AA
ISSUE C

DATE 22 AUG 2023



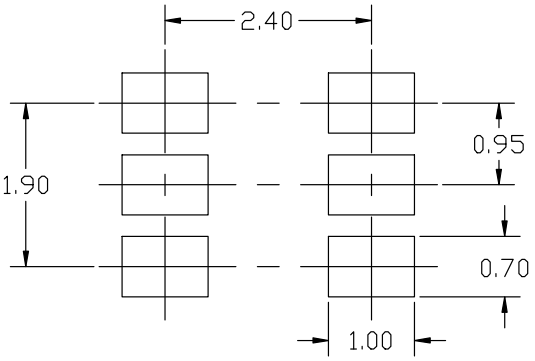




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

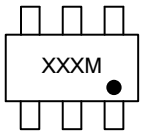
	MILLIMETERS		
DIM	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	0.01	0.06	0.10
A2	0.80	0.90	1.00
b	0.25	0.37	0.50
c	0.10	0.18	0.26
D	2.90	3.00	3.10
E	1.30	1.50	1.70
e	0.85	0.95	1.05
L	0.20	0.40	0.60
H_E	2.50	2.75	3.00
M	0°	–	10°



RECOMMENDED
MOUNTING FOOTPRINT*

* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLE 20:
PIN 1. COLLECTOR 1
2. BASE 2
3. EMITTER 2
4. COLLECTOR 2
5. BASE 1
6. EMITTER 1

STYLE 21:
PIN 1. COLLECTOR 1
2. EMITTER 2
3. BASE 2
4. COLLECTOR 2
5. EMITTER 1
6. BASE 1

DOCUMENT NUMBER:	**98AON13505D**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.	
DESCRIPTION:	**SC74−6 3.00x1.50x0.90, 0.95P**		**PAGE 1 OF 1**

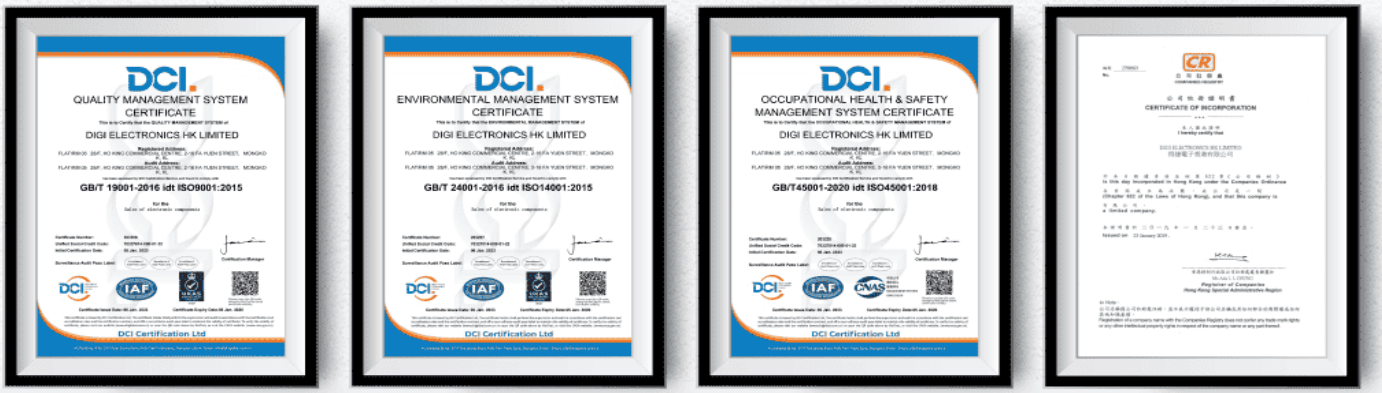
ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:
Technical Library: www.onsemi.com/design/resources/technical−documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support
For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales

OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.